

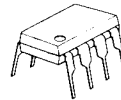
NJM4250

The NJM4250 is extremely versatile programmable monolithic operational amplifiers. A single external master bias current setting resistor programs the input bias current, input offset current, quiescent power consumption, slew rate, input noise, and the gain-bandwidth product. The device is a truly general purpose operational amplifier.

■ Package Outline

■ Absolute Maximum Ratings (Ta=25°C)

Supply Voltage	V ⁺ /V ⁻	±18V
Differential Input Voltage	V _{ID}	±30V
Input Voltage(note)	V _{IC}	±15V
Power Dissipation	P _D (D-Type)	500mW
	(M,E-Type)	300mW
Set Current	I _{SET}	150μA
Operating Temperature Range	T _{opr}	-20~+75°C
Storage Temperature Range	T _{sig}	-40~+125°C



NJM4250D



NJM4250M



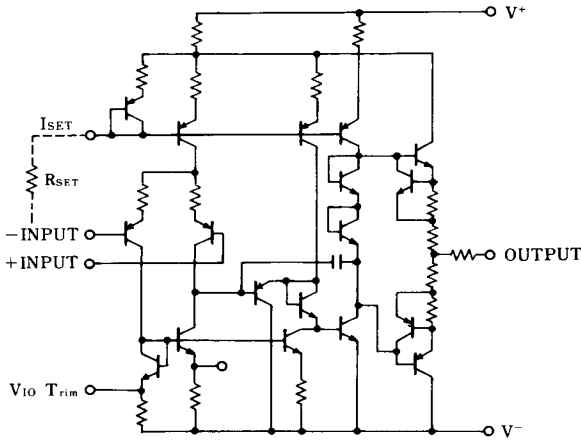
NJM4250E

(note) For supply voltage less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

■ Electrical Characteristics (Ta=25°C, V⁺/V⁻ = ±15V)

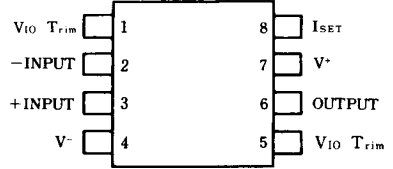
Parameter	Symbol	Test Condition	I _{SET} =1μA		I _{SET} =10μA		Unit
			Min.	Max.	Min.	Max.	
Input Offset Voltage 1	V _{IO 1}	R _S ≤ 100kΩ	—	5	—	6	mV
Input Offset Voltage 2	V _{IO 2}	V ⁺ /V ⁻ = ±1.5V, R _S ≤ 100kΩ	—	5	—	6	mV
Input Offset Current	I _{IO}		—	6	—	20	nA
Input Bias Current 1	I _{B 1}		—	10	—	75	nA
Input Bias Current 2	I _{B 2}	V ⁺ /V ⁻ = ±1.5V	—	10	—	75	nA
Large Signal Voltage Gain 1	A _{v 1}	V _o = ±10V, R _L ≥ 100kΩ	96	—	—	—	dB
Large Signal Voltage Gain 2	A _{v 2}	V _o = ±10V, R _L ≥ 10kΩ	—	—	96	—	dB
Supply Current 1	I _{CC 1}		—	11	—	100	μA
Supply Current 2	I _{CC 2}	V ⁺ /V ⁻ = ±1.5V	—	8	—	90	μA
Input Common Mode Voltage Range 1	V _{ICM 1}		±13.5	—	±13.5	—	V
Input Common Mode Voltage Range 2	V _{ICM 2}	V ⁺ /V ⁻ = ±1.5V	±0.6	—	±0.6	—	V
Maximum Output Voltage Swing 1	V _{OM 1}	R _L ≥ 100kΩ	±12	—	—	—	V
Maximum Output Voltage Swing 2	V _{OM 2}	V ⁺ /V ⁻ = ±1.5V, R _L ≥ 100kΩ	±0.6	—	—	—	V
Maximum Output Voltage Swing 3	V _{OM 3}	R _L ≥ 10kΩ	—	—	±12	—	V
Maximum Output Voltage Swing 4	V _{OM 4}	V ⁺ /V ⁻ = ±1.5V, R _L ≥ 10kΩ	—	—	±0.6	—	V
Common Mode Rejection Ratio	CMR	R _S ≤ 10kΩ	70	—	70	—	dB
Supply Voltage Rejection Ratio	SVR	R _S ≤ 10kΩ	74	—	74	—	dB

Equivalent Circuit

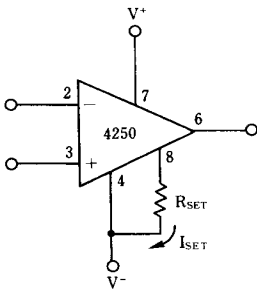


Connection Diagram

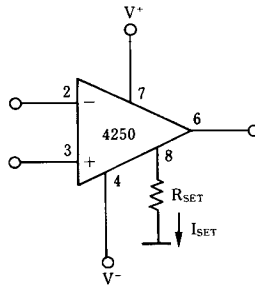
(D.M.E-Type)
(Top View)



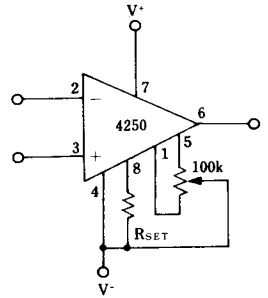
Typical Applications (I_{SET}, V_{IO} Adjustment)



$$I_{SET} = \frac{V^+ + |V^-| - 0.5}{R_{SET}}$$



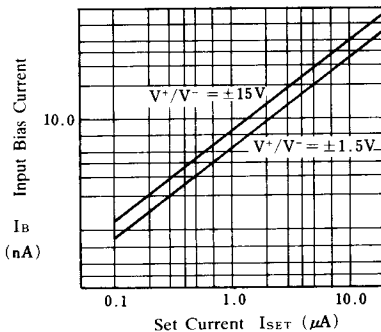
$$I_{SET} = \frac{V^+ - 0.5}{R_{SET}}$$



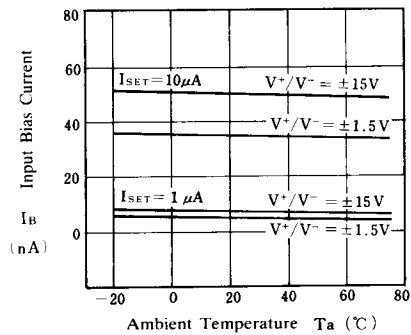
Offset Adjustment

Typical Characteristics

Input Bias Current vs. Set Current
(T_a = 25°C)



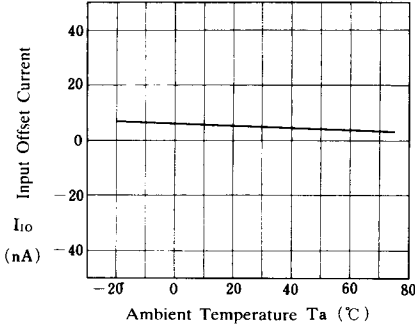
Input Bias Current vs. Ambient Temperature



■ Typical Characteristics

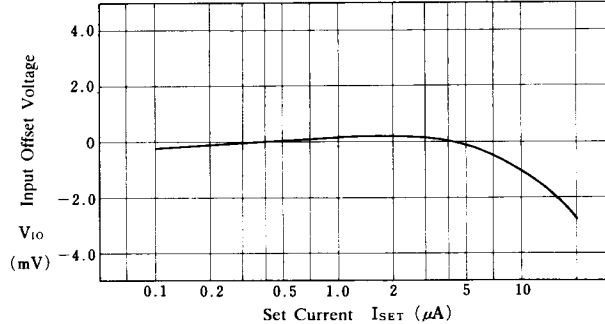
Input Offset Current vs. Ambient Temperature

($I_{SET} = 10\mu A$, $\pm 1.5V \leq V^+/V^- \leq \pm 15V$)



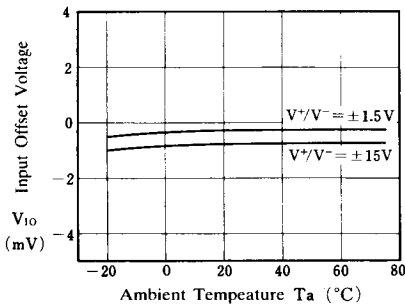
Input Offset Voltage vs. Set Current

($\pm 1.5V \leq V^+/V^- \leq \pm 15V$, $T_a = 25^\circ C$)



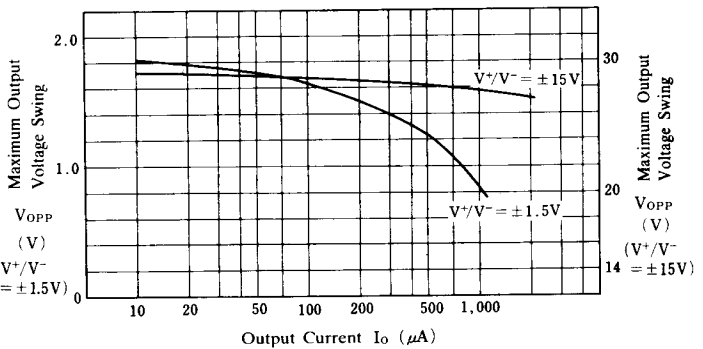
Input Offset Voltage vs. Ambient Temperature

($I_{SET} = 10\mu A$)



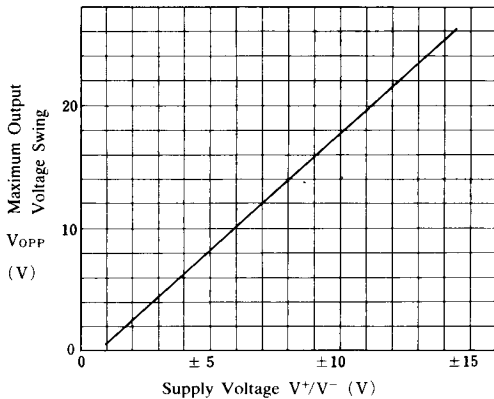
Maximum Output Voltage Swing vs. Output Current

($I_{SET} = 10\mu A$, $T_a = 25^\circ C$)



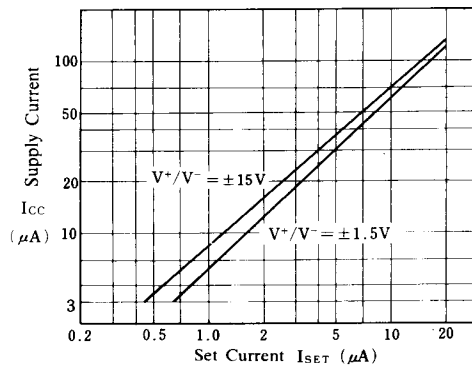
Maximum Output Voltage Swing vs. Supply Voltage

($1\mu A \leq I_{SET} \leq 10\mu A$, $R_L = 10k\Omega$, $T_a = 25^\circ C$)

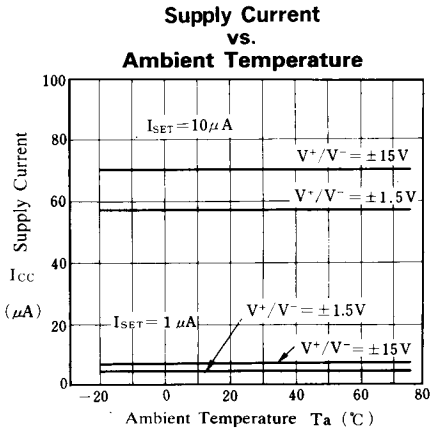


Supply Current vs. Set Current

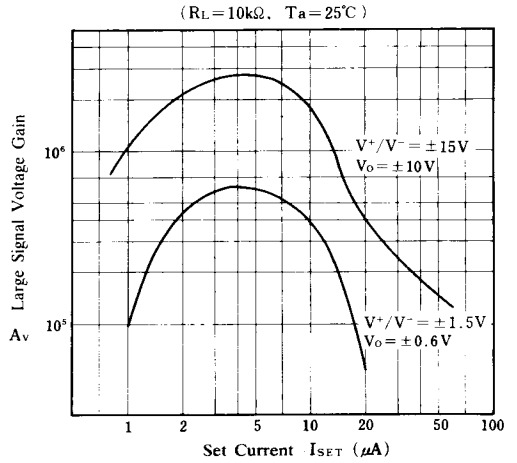
($T_a = 25^\circ C$)



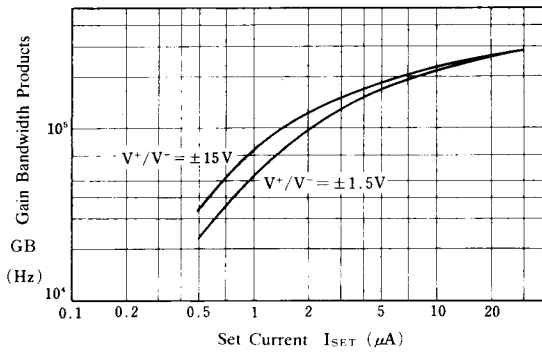
■ Typical Characteristics



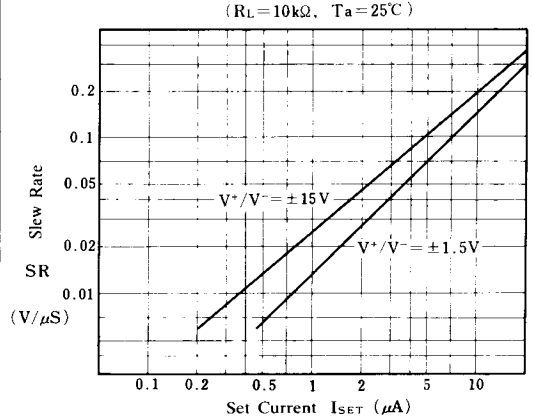
Open Loop Voltage Gain vs. Set Current



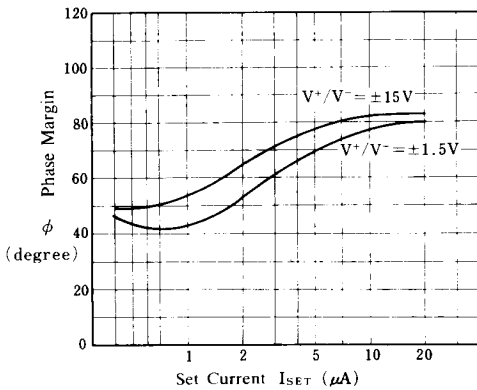
Gain Bandwidth Product vs. Set Current



Slew Rate vs. Set Current



Phase Margin vs. Set Current



■ Typical Applications

500nW 10times Inverting Amplifier

